

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

PNP Epitaxial Planar Silicon Transistor

CPH6153 — Load Switch Applications

Applications

· Load switch, DC-DC converter, motor drivers, charger

Features

- · Adoption of MBIT process
- · Large current capacity
- · Low collector-to-emitter saturation voltage
- · High speed switching
- Ultrasmall-sized package permitting applied sets to be made small and slim (0.9mm)
- · High allowable power dissipation
- · IECO is guaranteed for preventing reverse flow from the collector to the emitter

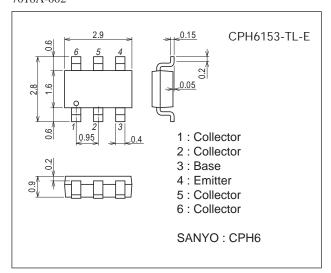
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-20	V
Collector-to-Emitter Voltage	VCEO		-20	V
Emitter-to-Base Voltage	V _{EBO}		-5	V
Collector Current	IC		-3	А
Collector Current (Pulse)	ICP		-5	А
Base Current	ΙΒ		-600	mA
Collector Dissipation	PC	When mounted on ceramic substrate (600mm ² ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7018A-002



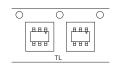
Product & Package Information

• Package : CPH6

• JEITA, JEDEC : SC-74, SOT-26, SOT-457

• Minimum Packing Quantity : 3,000 pcs./reel

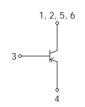
Packing Type: TL



Marking



Electrical Connection

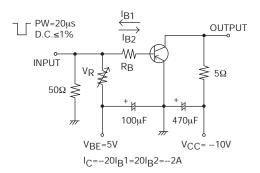


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Electrical Characteristics at Ta=25°C

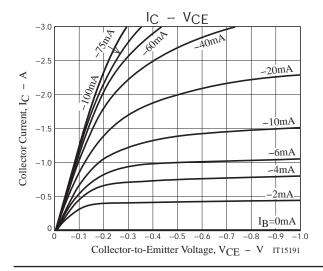
Parameter	Cumbal	Conditions	Ratings			Linit	
Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector Cutoff Current	ICBO	V _{CB} = -20V, I _E =0A			-0.1	μΑ	
Emitter Cutoff Current	I _{EBO}	V _{EB} = -4V, I _C =0A			-0.1	μΑ	
Emitter Cutoff Current	IECO	V _{EC} = -4.5V, I _B =0A			-1	μΑ	
DC Current Gain	hFE	V _{CE} = -2V, I _C = -100mA	200		560		
Gain-Bandwidth Product	fŢ	V _{CE} = -10V, I _C = -300mA		400		MHz	
Output Capacitance	Cob	V _{CB} = -10V, f=1MHz		22		pF	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = -1.5A, I _B = -75mA		-130	-195	mV	
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = -1.5A, I _B = -75mA		-0.93	-1.2	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC= -10μA, IE=0A	-20			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC= -1mA, RBE=∞	-20			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E = -10μA, I _C =0A	-5			V	
Turn-On Time	ton	See specified Test Circuit.		35		ns	
Storage Time	t _{stg}	See specified Test Circuit.		65		ns	
Fall Time	tf	See specified Test Circuit.		12		ns	

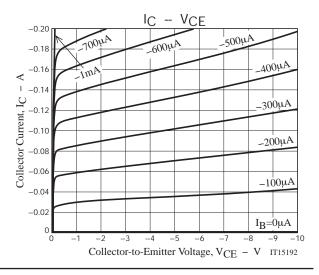
Switching Time Test Circuit

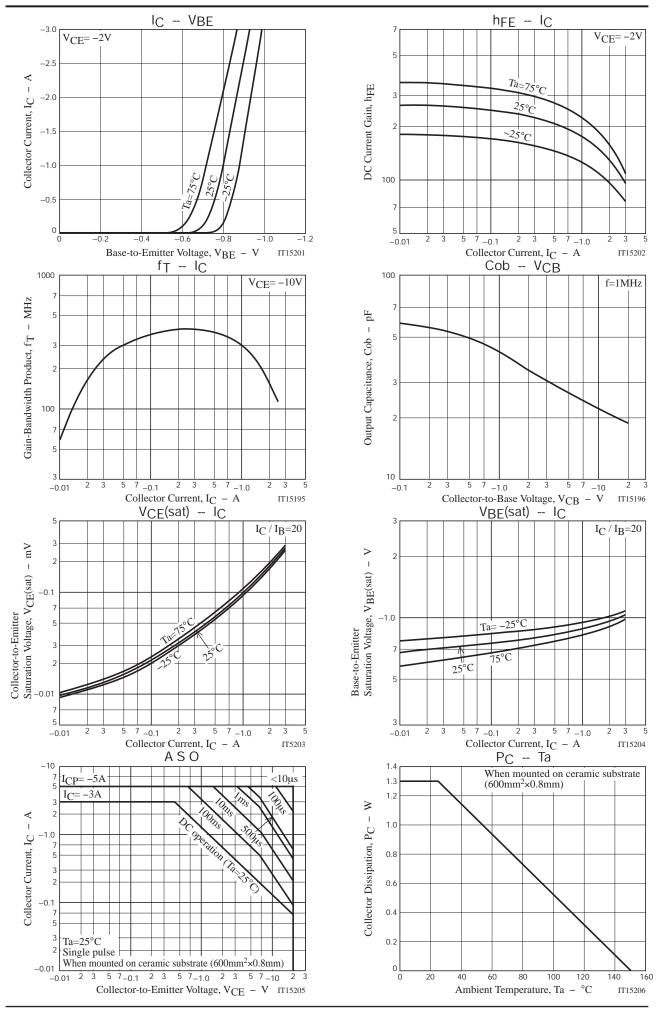


Ordering Information

Device Package		Shipping	memo	
CPH6153-TL-E CPH6		3,000pcs./reel	Pb Free	





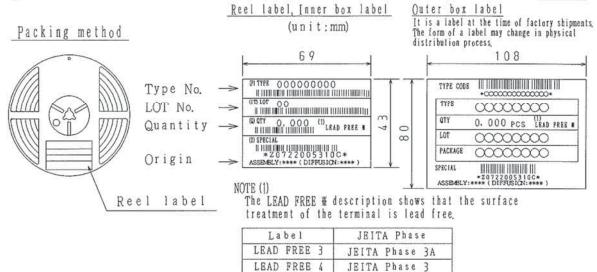


Embossed Taping Specification

CPH6153-TL-E

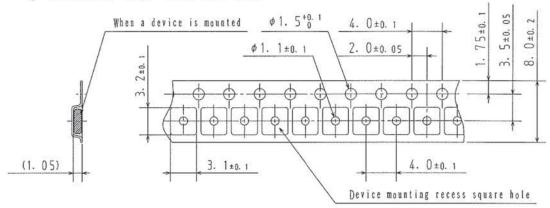
1. Packing Format

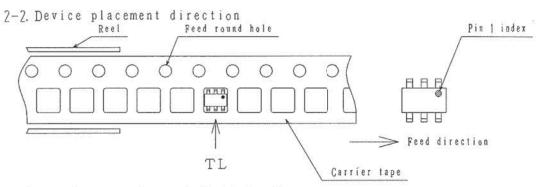
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format		
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
СРН6	СРН6	3, 000	15, 000	90, 000		6 inner boxes contained Dimensions:mm (external) $440 \times 195 \times 210$	



7. Taping configuration

2-1. Carrier tape size (unit:mm)





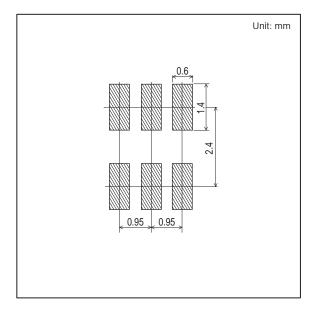
Those with pin 1 index on the feed hole side TL

Outline Drawing

CPH6153-TL-E

Mass (g) Unit 0.015 For reference mm 0. 15^{+0. 1}_{-0. 05} 2. 9±0. 1 0.6±0.1 A 0. 2±0.1 [*1][*1] 0. 05±0.05 2. 8±0. 15 . 6±0. 1 [*1] - \$ 0.95 0. 4±0. 1 M A PIN#1 0.05 \$ *1:Lot indication

Land Pattern Example



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